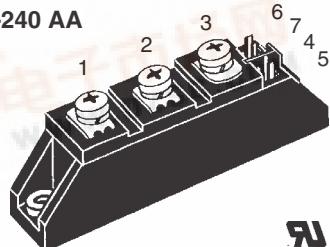



**MCC 56
MCD 56**

Thyristor Modules Thyristor/Diode Modules

**I_{TRMS} = 2x100 A
I_{TAVM} = 2x64 A
V_{RRM} = 800-1800 V**

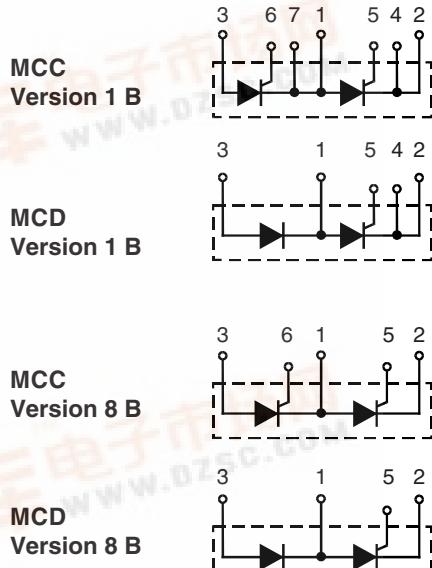
TO-240 AA



| V _{RSM} | V _{RRM} | Type | V _{DSM} | V _{DRM} | | | |
|------------------|------------------|-----------|------------------|------------------|-----------|---------------|-----|
| V | V | Version | 1 B | 8 B | Version | 1 B | 8 B |
| 900 | 800 | MCC 56-08 | io1 B / io8 B | | MCD 56-08 | io1 B / io8 B | |
| 1300 | 1200 | MCC 56-12 | io1 B / io8 B | | MCD 56-12 | io1 B / io8 B | |
| 1500 | 1400 | MCC 56-14 | io1 B / io8 B | | MCD 56-14 | io1 B / io8 B | |
| 1700 | 1600 | MCC 56-16 | io1 B / io8 B | | MCD 56-16 | io1 B / io8 B | |
| 1900 | 1800 | MCC 56-18 | io1 B / io8 B | | MCD 56-18 | io1 B / io8 B | |

| Symbol | Conditions | Maximum Ratings | | |
|---------------------------------------|---|---|---------------|------------------|
| I _{TRMS} , I _{FRMS} | T _{VJ} = T _{VJM} | 100 | A | |
| I _{TAVM} , I _{FAVM} | T _C = 83°C; 180° sine | 64 | A | |
| | T _C = 85°C; 180° sine | 60 | A | |
| I _{TSM} , I _{FSM} | T _{VJ} = 45°C; V _R = 0 | t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine | 1500 | A |
| | T _{VJ} = T _{VJM} V _R = 0 | t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine | 1350 | A |
| | | | 1450 | A |
| ∫i ² dt | T _{VJ} = 45°C V _R = 0 | t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine | 11 200 | A ² s |
| | T _{VJ} = T _{VJM} V _R = 0 | t = 10 ms (50 Hz), sine t = 8.3 ms (60 Hz), sine | 10 750 | A ² s |
| (di/dt) _{cr} | T _{VJ} = T _{VJM} f = 50 Hz, t _p = 200 μs V _D = 2/3 V _{DRM} | repetitive, I _T = 150 A | 150 | A/μs |
| | I _G = 0.45 A di _G /dt = 0.45 A/μs | non repetitive, I _T = I _{TAVM} | 500 | A/μs |
| (dv/dt) _{cr} | T _{VJ} = T _{VJM} ; R _{GK} = ∞; method 1 (linear voltage rise) | V _{DR} = 2/3 V _{DRM} | 1000 | V/μs |
| P _{GM} | T _{VJ} = T _{VJM} ; I _T = I _{TAVM} | t _p = 30 μs t _p = 300 μs | 10 5 | W W |
| P _{GAV} | | | 0.5 | W |
| V _{RGM} | | | 10 | V |
| T _{VJ} | | | -40...+125 | °C |
| T _{VJM} | | | 125 | °C |
| T _{stg} | | | -40...+125 | °C |
| V _{ISOL} | 50/60 Hz, RMS; I _{ISOL} ≤ 1 mA; | t = 1 min t = 1 s | 3000 3600 | V~ |
| M _d | Mounting torque (M5) Terminal connection torque (M5) | | 2.5-4.0/22-35 | Nm/lb.in. |
| Weight | Typical including screws | | 90 | g |

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions



Features

- International standard package, JEDEC TO-240 AA
- Direct copper bonded Al₂O₃ -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873
- Gate-cathode twin pins for version 1B

Applications

- DC motor control
- Softstart AC motor controller
- Light, heat and temperature control

Advantages

- Space and weight savings
- Simple mounting with two screws
- Improved temperature and power cycling
- Reduced protection circuits

| Symbol | Conditions | Characteristic Values | |
|--------------------|---|-----------------------|-----------|
| I_{RRM}, I_{DRM} | $T_{VJ} = T_{VJM}; V_R = V_{RRM}; V_D = V_{DRM}$ | 5 | mA |
| V_T, V_F | $I_T/I_F = 200 A; T_{VJ} = 25^\circ C$ | 1.57 | V |
| V_{T0} | For power-loss calculations only ($T_{VJ} = 125^\circ C$) | 0.85 | V |
| r_T | | 3.7 | $m\Omega$ |
| V_{GT} | $V_D = 6 V; T_{VJ} = 25^\circ C$ | 1.5 | V |
| | $T_{VJ} = -40^\circ C$ | 1.6 | V |
| I_{GT} | $V_D = 6 V; T_{VJ} = 25^\circ C$ | 100 | mA |
| | $T_{VJ} = -40^\circ C$ | 200 | mA |
| V_{GD} | $T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$ | 0.2 | V |
| I_{GD} | | 10 | mA |
| I_L | $T_{VJ} = 25^\circ C; t_p = 10 \mu s; V_D = 6 V$ | 450 | mA |
| | $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$ | | |
| I_H | $T_{VJ} = 25^\circ C; V_D = 6 V; R_{GK} = \infty$ | 200 | mA |
| t_{gd} | $T_{VJ} = 25^\circ C; V_D = \frac{1}{2} V_{DRM}$ | 2 | μs |
| | $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$ | | |
| t_q | $T_{VJ} = T_{VJM}; I_T = 150 A, t_p = 200 \mu s; -di/dt = 10 A/\mu s$ | typ. 150 | μs |
| | $V_R = 100 V; dv/dt = 20 V/\mu s; V_D = \frac{2}{3} V_{DRM}$ | | |
| Q_s | $T_{VJ} = T_{VJM}; I_T, I_F = 50 A, -di/dt = 3 A/\mu s$ | 100 | μC |
| I_{RM} | | 24 | A |
| R_{thJC} | per thyristor/diode; DC current | 0.45 | K/W |
| | per module | 0.225 | K/W |
| R_{thJK} | per thyristor/diode; DC current | 0.65 | K/W |
| | per module | 0.325 | K/W |
| d_s | Creepage distance on surface | 12.7 | mm |
| d_A | Strike distance through air | 9.6 | mm |
| a | Maximum allowable acceleration | 50 | m/s^2 |

Optional accessories for module-type MCC 56 version 1 B
 Keyed gate/cathode twin plugs with wire length = 350 mm, gate = yellow, cathode = red
 Type ZY 200L (L = Left for pin pair 4/5) } UL 758, style 1385,
 Type ZY 200R (R = right for pin pair 6/7) } CSA class 5851, guide 460-1-1

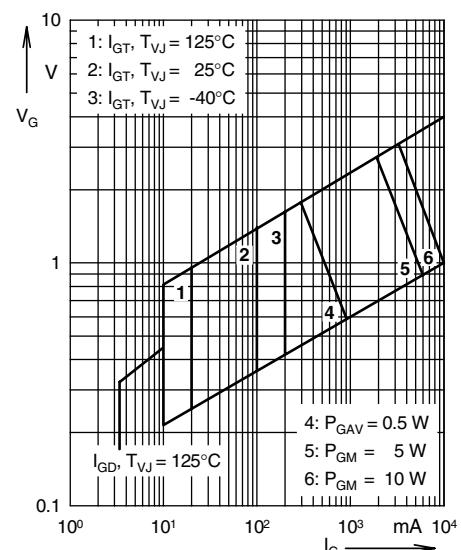


Fig. 1 Gate trigger characteristics

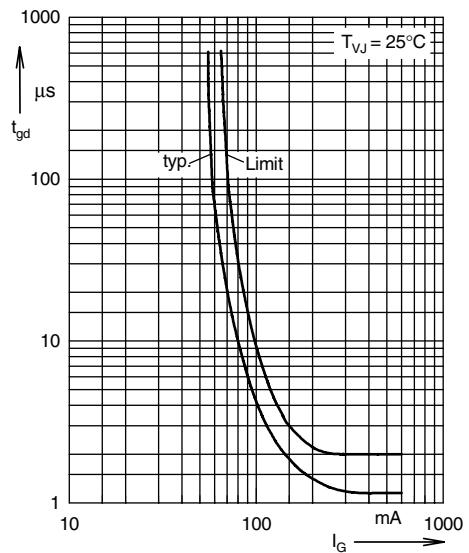
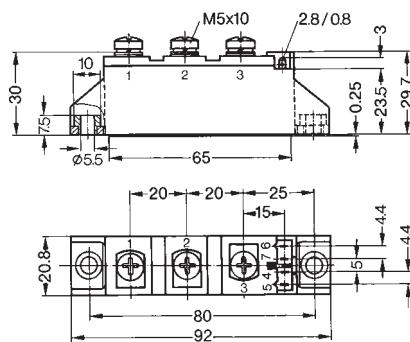


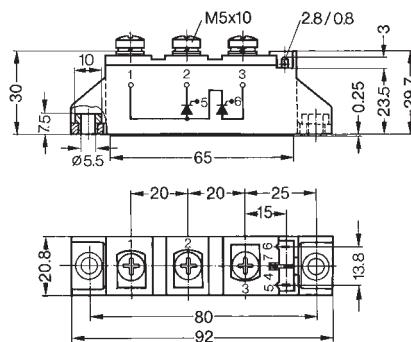
Fig. 2 Gate trigger delay time

Dimensions in mm (1 mm = 0.0394")

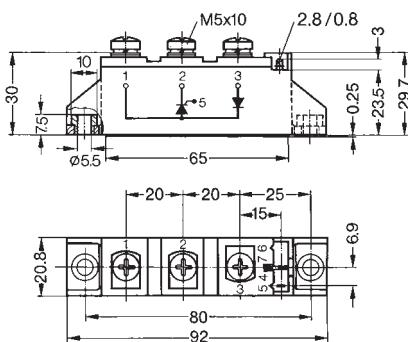
MCC / MCD / MDC Version 1 B



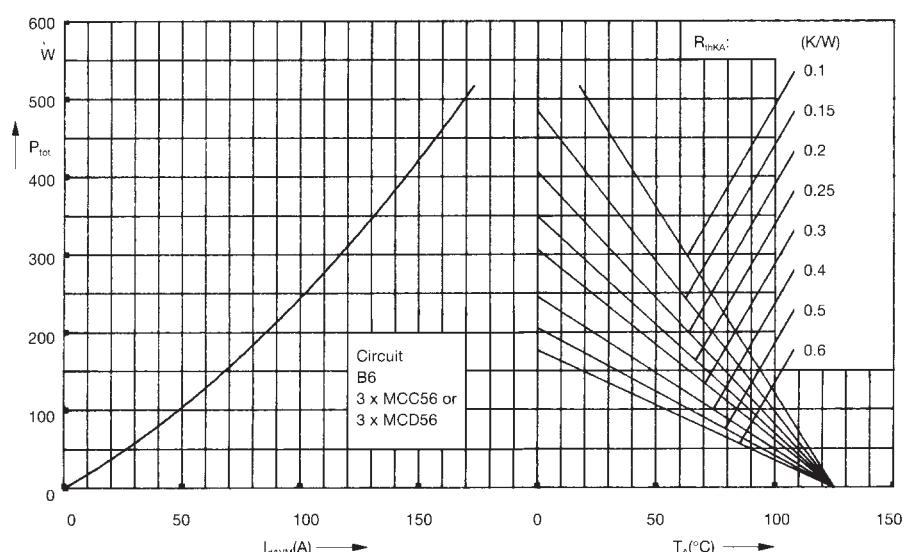
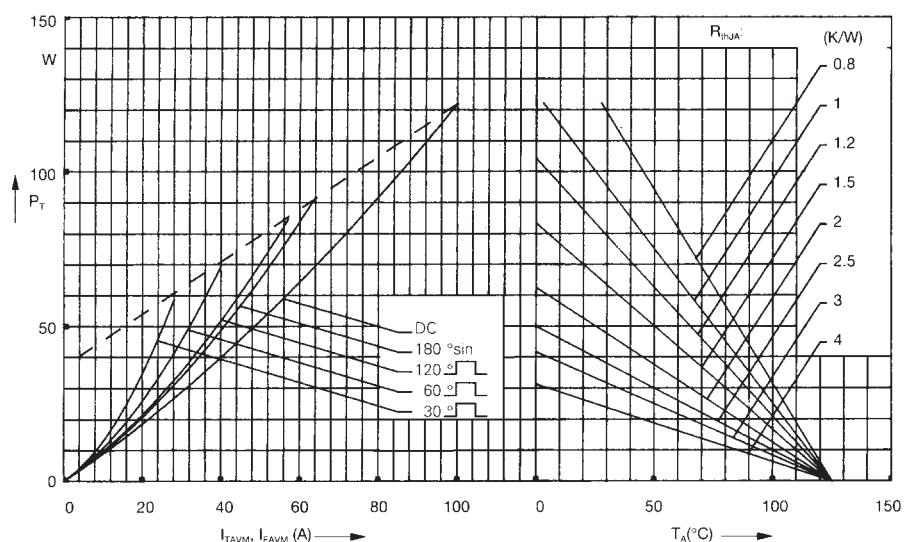
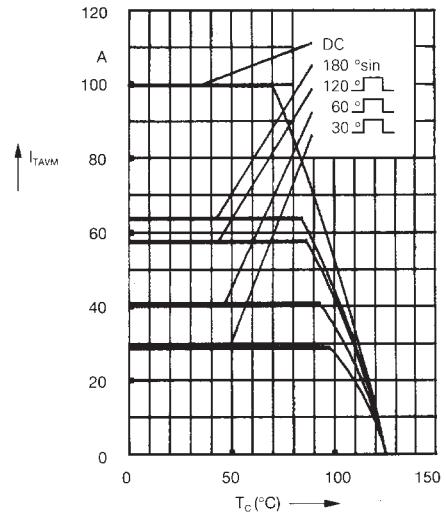
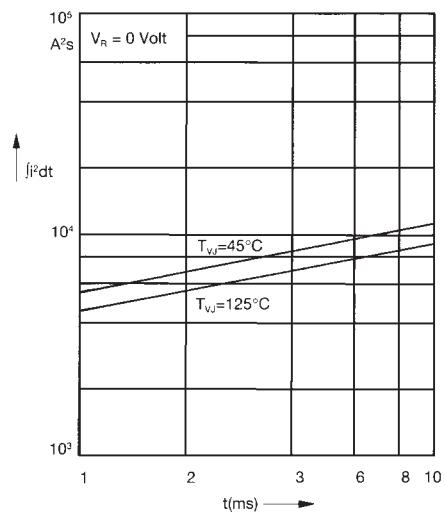
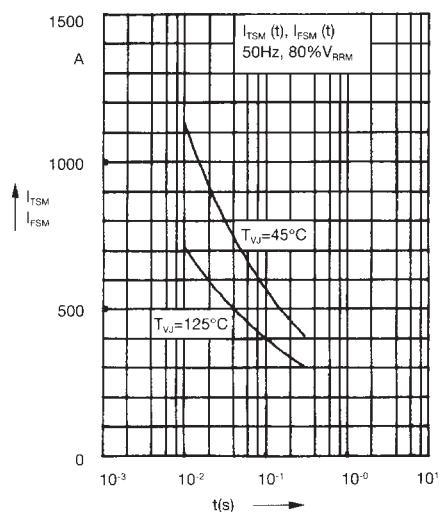
MCC Version 8 B

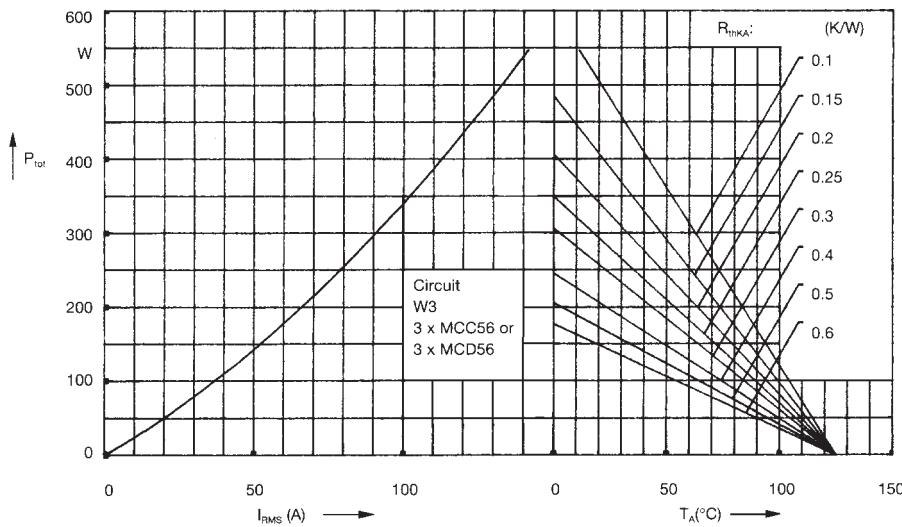


MCD Version 8 B

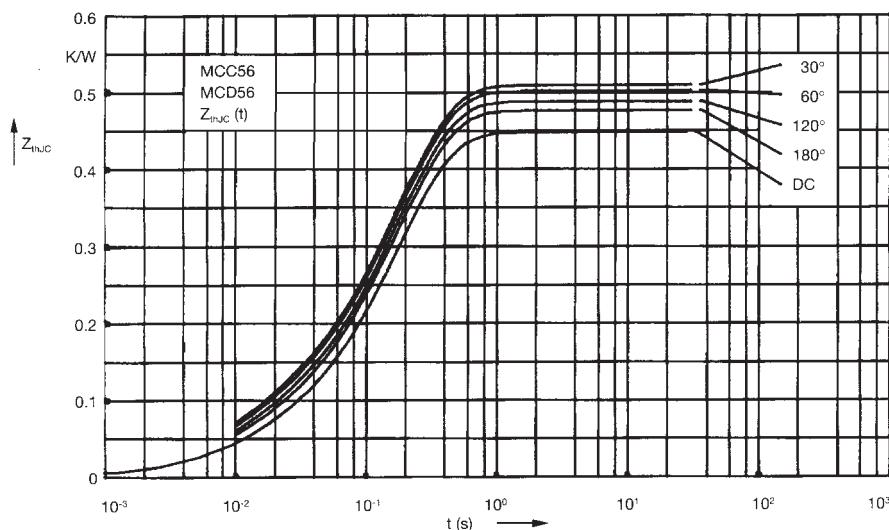


Version 1 or 8 without B in typ designation = without insert in mounting holes





**Fig. 7 Three phase AC-controller:
Power dissipation versus RMS
output current and ambient
temperature**



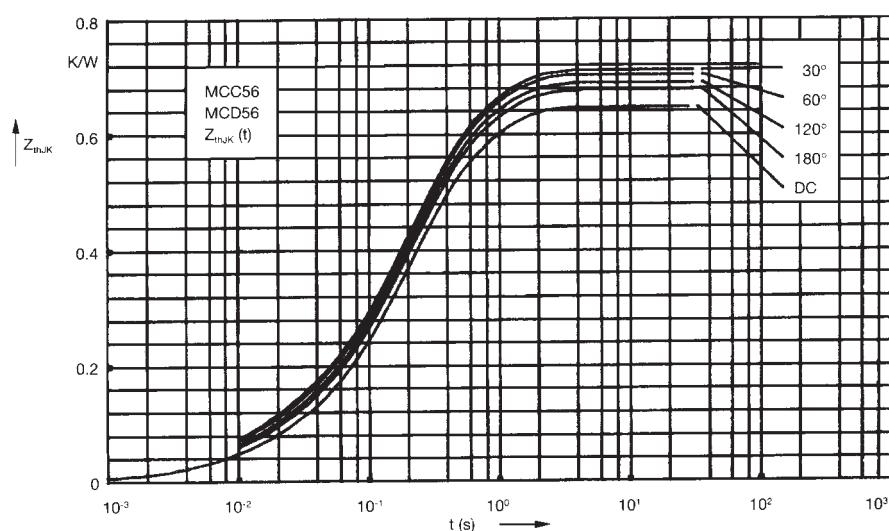
**Fig. 8 Transient thermal impedance
junction to case (per thyristor or
diode)**

R_{thJC} for various conduction angles d:

| d | R_{thJC} (K/W) |
|------|------------------|
| DC | 0.45 |
| 180° | 0.47 |
| 120° | 0.49 |
| 60° | 0.505 |
| 30° | 0.52 |

Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.014 | 0.015 |
| 2 | 0.026 | 0.0095 |
| 3 | 0.41 | 0.175 |



**Fig. 9 Transient thermal impedance
junction to heatsink (per thyristor
or diode)**

R_{thJK} for various conduction angles d:

| d | R_{thJK} (K/W) |
|------|------------------|
| DC | 0.65 |
| 180° | 0.67 |
| 120° | 0.69 |
| 60° | 0.705 |
| 30° | 0.72 |

Constants for Z_{thJK} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.014 | 0.015 |
| 2 | 0.026 | 0.0095 |
| 3 | 0.41 | 0.175 |
| 4 | 0.2 | 0.67 |